# **SIZE MATTERS**

# Mechanical Properties of Nano-sized Single Crystals

## Julia R. Greer

But really it's the work of graduate student A.T. Jennings and post-doc Ju-Young Kim

Division of Engineering and Applied Science California Institute of Technology



# **Materials and Length Scales**



In nanocrystals (quantum dots, nanowires, nanotubes, etc.) size modification tunes a variety of properties: optical, electronic, plasmonic, thermal, acoustic, etc. which brings into question material structural integrity



## **Background: Nanoindentation**



**Disadvantages:** Strain gradients, complex stress-strain calculations, limited plasticity information **Advantages**: Elastic properties, hardness, deformation volume control

Great need for experimental techniques testing mechanical deformation at nano-scale *without* strain gradients!

## Micro-compression experimental setup



- Flat punch indenter tip
- Constant displacement rate

#### Nano-pillar fabrication: Mainly Focused Ion Beam (FIB)



#### Image after compression



100



## Nano-pillar Fabrication Methods

#### Focused Ion Beam

**FIB-less** 



## FIB-less fabrication: E-beam Litho => Electroplating

#### 1. E-beam patterning



Α



#### 4. Free-standing 3. Pillars in PMMA Matrix pillar array



M.J. Burek and J.R. Greer Nano Lett 10, 69-76 (2009)

#### Nano-Louvre

## rough Novel Synthesis

Cu					
	adress costs				
Q	Ŷ	Q	9	9	Ŷ
Q	Ŷ	Q	Q	Ŷ	Ŷ
የ	Ŷ	Ŷ	Ŷ	Ą	Q
ę	Ŷ	Q	Ŷ	Ŷ	Ŷ

#### Nano-Popsicles



1/21/2011 HV mag WD HFW det 2:35:30 PM 10.00 kV 50 000 x 9.7 mm 5.97 μm ETD — 2 µm

## Single Crystals: Ubiquitous Size Effect



#### **Dislocation Nucleation-controlled plasticity**





J.R. Greer, J.Th. de Hosson Review: Plasticity in small-sized metallic systems Prog Mat Sci (2011)

## "Smaller is Stronger" and Strain Bursts

#### Predeformation

Postdeformation



Size effects with stochastic stress-strain signature and size effects are identical



# Dislocation starvation and nucleation: source-controlled plasticity

In a nano-pillar (deeply in sub-micron regime) with non-zero initial dislocation density



Under compression dislocations leave the crystal faster than they multiply

New dislocations have to be nucleated WHERE?

Coined hardening by dislocation starvation, occurs only in small volumes and not in bulk crystals.

Greer, J.R. and Nix, W.D. Phys. Rev. B, 73, 24 (2006)

## Insights into Deformation mechanisms: TEM

How do we TEM the same nano-pillars before and after deformation???



We test them directly on TEM grid!

## Single Crystalline (FIB-less) Pillars are NOT dislocation-free



Jennings et al. Phys Rev Lett, 104, 135503 (2010)

**Dislocation Density:** 

 $\rho = L/\pi R^2 h$ 

 $\rho = 1.46 \text{ x } 10^{14} \text{ m}^{-2}$ 

Relatively high!

BUT important to recognize: the lowest attainable non-zero dislocation density is 1 x 10<sup>12</sup> m<sup>-2</sup>



(corresponds to a 7-atom loop in 121nm x 188 nm cylindrical volume)



## **Dislocation Nucleation Sources**

**FRANK-READ** Source (a.k.a. conventional)  $(\Omega \sim 100 - 1000b^3)$ 

"Truncated" or SINGLE ARM Source (micron-sized pillars)  $(\Omega \sim 50 - 500b^3)$ 

### SURFACE Source $(\Omega \sim 1 - 10b^3)$



One [101] end-pinned screw dislocation in a (111) glide plane.



Parthasarathy et al. Scripta Mat (2007) Rao et al. Acta Mat (2008) Tang et al Phys Rev Lett (2008) Oh et al. Nature Mat (2009) Weinberger et al. Scripta Mat (2010)

$$\Omega_{SAS} = \frac{\Omega_{F-R}}{2}$$



Gall et al Nano Letters (2004) Diao et al Acta Mat (2006) Zhu et al Phys Rev Lett (2008) Lu et al Nature Nano (2010)

Activation volume can be experimentally determined by varying strain rate:

 $\Omega = k_B T \frac{\partial \ln(\dot{\gamma})}{\hat{\gamma}}$ 



# **Dislocation Nucleation Sources**

#### Single-arm source

 $\begin{bmatrix} 0\overline{1}1 \end{bmatrix}$ 

[111]

 $\left[\overline{2}11\right]$ 



(SAS TEM movie courtesy M. Legros)

MD movie courtesy of C. Weinberger

**Surface source** 

(SS TEM movie courtesy J. Huang)



Tang, Schwarz, Espinosa, Phys. Rev. Lett. (2007) Oh, S.H. et al, Nature Mater. (2009) Zheng, H. et al. Nature Comm. (2010)

## Surface vs. Single-Arm Sources



# Atomistics of Dislocation Motion in Pillars: Molecular Dynamics Simulations

18nm-diameter Au pillar Constant load = 500 MPa 24nm-diameter Mo pillar Constant Load = 9 GPa



## Mechanical Properties of [001] bcc nano-pillars



- 1. Stress-strain signature is stochastic, with intermittent strain bursts
  - 2. Power-law size effects present in bcc nano structures
- 3. Tension-Compression asymmetry is present and is more pronounced in samples with larger diameters than smaller ones



Kim, J.-Y., Jang, D., Greer, J.R. Acta Mater., 58 2355-2363 (2010)

# **Origins of Different Size Effects**





Overcoming Peierls potential is KEY in BCC Plasticity





Critical temperature (K)



- Dislocations propagate by kink-pair nucleation
- Must overcome Peierls potential → requires high stresses or T
- Screw dislocations are much slower than edge dislocations → dominate deformation below

Kim, J.-Y., Jang, D., Greer, J.R. Acta Mater., 58 2355-2363 (2010)

Kim, J.-Y., Greer, J.R. Appl. Phys. Lett. (2008)

# **Origins of Tension-Compression Asymmetry**

#### Different gripping constraints



1. Intrinsic effect of BCC structure

 $(\bar{1}10)$ 

- Shear stresses in positive and negative <111> are not equivalent (except on {110} planes)

-Twinning vs. Anti-twinning on {112} planes (not mirror)

(a)



ABCDEFABCDEF

shear stress components

winning  $\gamma < 0$ [111]~ mrssp (011) Antitwinning





A.S. Argon "Strengthening Mechanisms in Crystal Plasticity" (2008)

## Effects of Crystallographic Orientation: [001] vs. [011]



J.Y. Kim, D. Jang, and J.R. Greer Int J Plasticity (in press, 2011)

## Effect of Orientation: [001] vs. [011]



J.Y. Kim, D. Jang, and J.R. Greer Int J Plasticity (in press, 2011)

## Diminishing effects of screw dislocations with smaller size



Screw dislocations appear to play a more important role in flow stress (rather than yield stress) and in larger (rather than smaller) pillars

Groger and Vitek, Phil. Mag. Lett. (2007)

Weinberger and Cai, PNAS (2008)



Slip System	Schmid
( 1 01)[111]	0.41
(-211)[111]	0.24
(-1-12)[111]	0.47
(-211)[111]	0.47
(-1-12)[111]	0.24
	Slip System ( 1 01)[111] (-211)[111] (-1-12)[111] (-211)[111] (-1-12)[111]

Opposite  $\chi$  for  $(\overline{1} \ \overline{1} \ 2)$  and  $(\overline{2} 11)$  planes => diametrically opposite twinning-antitwinning slip - [001] orientation:  $(\overline{1} \ \overline{1} \ 2)$  shears in the twinning sense => Compression >Tension - [011] orientation:  $(\overline{2} 11)$  shears in the antitwinning sense => Tension > Compression

## Compression >Tension for [100] Mo while Tension >Compression for [110] Mo



J.Y. Kim, D. Jang, and J.R. Greer Int J Plasticity (in press, 2011)

# **Deformation Mechanisms and Size Effects**

Plasticity carriers: **Dislocations** 

Plasticity carriers: **Dislocations + grain/twin boundaries** 



Low and Trial, Acta Met. (1962) Fe-3% Si

Single Crystals (Au, Mo, Nb, etc.)



Plasticity carriers: **Shear Transformation Zones (STZs)** 



Metallic glasses See talk by D. Jang on Thursday at 2pm

Plasticity carriers: STZs + dislocations



Amorphous/ Nanocrystalline **Nanolaminates** 

See talk by J.-Y. Kim on Thursday at 2:20pm (1-D Mechanics)

Increasing disorder (introducing boundaries and amorphous-ness)

## Summary and Acknowledgements

- Single crystalline Cu (fcc) nano-pillars fabricated without FIB yet with similar dislocation densities exhibit an identical size effect and stochastic intermittent flow as FIB-produced ones
- Dislocation starvation followed by surface source nucleation likely dominates plasticity at sizes below ~125nm
- Dislocation multiplication through single-arm source operation likely governs plasticity in pillars above ~125nm diameters
- Single crystalline Cu nano-pillars exhibit significant strain rate sensitivity at very small sizes, possibly corresponding to activation of surface sources
- Body-centered (bcc) nano-pillars also exhibit stochastic behavior, but much more complex size effects and tension-compression asymmetry



# Introducing multiple boundaries

## **Single Crystals**



# Nano-twinned



## Nanocrystalline





## Nanocrystalline + Nano-twinned





Jang, D, Cai, W., Greer, J.R. Nano Letters (in press, 2011)

#### Stress vs. strain for each microstructure (D=500nm) **Nano-twinned:** Single crystalline d=8.8 nm (twin spacing) 500 1600 500 nm compression 400 1200 True Stress (MPa) 300 Stress 800 200 400 100 0 0 0.02 0.04 0.06 0.08 0.1 0 0.2 0.3 0.0 0.1 **True Strain** Strain [-] Nanocrystalline/Nano-twinned: Nanocrystalline: 600 d=162nm (grain size) d=250nm (grain size) 500 d=6.7 nm (twin spacing) 500 400 Stress [MPa] 400 Stress [MPa] 300 300 200 200 100 100 0 0 0.02 0.04 0.06 0.08 0.1 0 Strain [-] 0.02 0.06 0.04 0.08 0

Strain [-]

Jang, D, Cai, W., Greer, J.R. Nano Letters (in press, 2011)

# Strength: Intrinsic (d) vs. Extrinsic (D)



Introducing twin boundaries increases strength Introducing grain boundaries decreases strength

Jang, D, Cai, W., Greer, J.R. Nano Letters (in press, 2011)





Transition to surface source operation may be manifested as deviation from the "athermal" size effect

Jennings, A.T., Li, J., Greer, J.R. (submitted, 2011)



## **Activation Volume for a Single-Arm Source**



## Moving onto BCC metals: Post-testing morphology

#### Pronounced shearing-off in tension

#### Crystallographic slip in compression



Kim, J.-Y., Jang, D., Greer, J.R. Acta Mater., 58 2355-2363 (2010)

Kim, J.-Y., et al. Scripta Mater. 61, 3 (2009)

## **TEM Sample Preparation: Phase 1**



1. Bring Micromanipulator almost in contact with lamella



## **TEM Sample Preparation: Phase 2**

Pt Needle

1. Bring in TEM grid

TEM grid

curr mag WD tilt det | 80 pA 350 x 19.5 mm 1 ° ETD 2 8 44

# Cross-section of lamella after some initial thinning

HV curr mag WD tilt det 5.00 kV 98 pA 19 998 x 4.9 mm 54 ° ETD re the needle

2 µm label

curr

mag

30 pA 6 500 x 19 4 mm

WD

° ETD

\_\_\_\_\_10

# **TEM Analysis of deformed pillars**

Nb

Мо



 $\Rightarrow$  Complex dislocation networks formed in Nb and Mo after compression  $\Rightarrow$  Partial dislocations generated on {110}, {112}, and {123} planes in Nb ⇒ Dislocation segments are straight (rather than wavy) in Nb implying rare cross-slip  $\Rightarrow$  Dislocation density increases in Nb and Mo after compression



Kim, J.-Y., Jang, D., Greer, J.R. Scripta Mater. 61, 3 (2009). TEM images by Dongchan Jang